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Contact us

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Email & Skype: info@chipsmall.com Web: www.chipsmall.com

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July 2016

FQD13N06L / FQU13N06L

N-Channel QFET® MOSFET

60 V, 11 A, 115 mΩ

Description

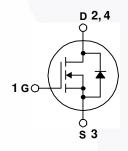
This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 11 A, 60 V, $R_{DS(on)}$ = 115 m Ω (Max) @ V_{GS} = 10 V, I_{D} = 5.5 A
- Low Gate Charge (Typ. 4.8 nC)
- · Low Crss (Typ. 17 pF)
- 100% Avalanche Tested
- Low Level Gate Drive Requirements Allowing Direct Operation form Logic Drivers







Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	l Parameter		FQD13N06LTM / FQU13N06LTU FQU13N06LTU_WS	Unit	
V _{DSS}	Drain-Source Voltage		60	V	
I _D	Drain Current - Continuous (T _C = 25°C)		11	Α	
	- Continuous (T _C = 100°C)		7	Α	
I _{DM}	Drain Current - Pulsed	(Note 1)	44	Α	
V _{GSS}	Gate-Source Voltage		± 20	V	
E _{AS}	Single Pulsed Avalanche Energy (N		90	mJ	
I _{AR}	Avalanche Current	(Note 1)	11	Α	
E _{AR}	Repetitive Avalanche Energy (2.8	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		7.0	V/ns	
P _D	Power Dissipation (T _A = 25°C) *		2.5	W	
	Power Dissipation (T _C = 25°C)		28	W	
	- Derate above 25°C		0.22	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
T _L	Maximum Lead Temperature for Soldering, 1/8" from Casefor Seconds		300	°C	

Thermal Characteristics

Symbol	Parameter	FQD13N06LTM FQU13N06LTU FQU13N06LTU_WS	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	2.5	
В	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	110	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (*1 in ² Pad of 2-oz Copper), Max.	50	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQD13N06LTM	FQD13N06L	D-PAK	Tape and Reel	330 mm	16 mm	2500 units
FQU13N06LTU	FQU13N06L	I-PAK	Tube	N/A	N/A	70 units
FQU13N06LTU_WS	FQU13N06LS	I-PAK	Tube	N/A	N/A	75 units

Electrical Characteristics T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Off Cha	aracteristics					
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		0.05		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 60 V, V _{GS} = 0 V			1	μΑ
		V _{DS} = 48 V, T _C = 150°C			10	μА
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 20 V, V _{DS} = 0 V			100	nA
I_{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		2.5	V
R _{DS(on)}	Static Drain-Source	V _{GS} = 10 V, I _D = 5.5 A		0.092	0.115	0
	On-Resistance	$V_{GS} = 5 \text{ V}, I_D = 5.5 \text{ A}$		0.115	0.145	Ω
g _{FS}	Forward Transconductance	V _{DS} = 25 V, I _D = 5.5 A		6		S
Dynam	ic Characteristics					
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		270	350	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		95	125	pF
C _{rss}	Reverse Transfer Capacitance			17	23	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 30 V, I _D = 6.8 A,		8	25	ns
t _r	Turn-On Rise Time	$R_{G} = 25 \Omega$		90	190	ns
t _{d(off)}	Turn-Off Delay Time	116 2032		20	50	ns
t _f	Turn-Off Fall Time	(Note 4)		40	90	ns
Qg	Total Gate Charge	V _{DS} = 48 V, I _D = 13.6 A,	/	4.8	6.4	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 5 V		1.6		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		2.7		nC
Drain-S	Source Diode Characteristics a	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				11	Α
I _{SM}	Maximum Pulsed Drain-Source Diode F	ce Diode Forward Current			44	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 11 A			1.5	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 13.6 A,		45	1	ns
41						

- **Notes:** 1. Repetitive rating : pulse-width limited by maximum junction temperature. 2. L = 870 μ H, I_{AS} = 11 A, V_{DD} = 25 V, R_G = 25 Ω , starting T_J = 25°C. 3. I_{SD} \leq 13.6 A, di/dt \leq 300 A/ μ s, V_{DD} \leq BV_{DSS}, starting T_J = 25°C. 4. Essentially independent of operating temperature.

Typical Characteristics

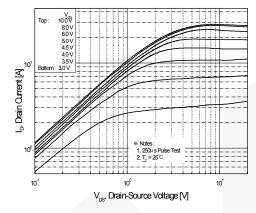


Figure 1. On-Region Characteristics

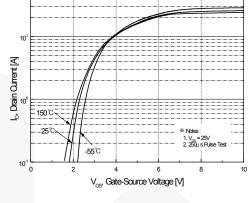


Figure 2. Transfer Characteristics

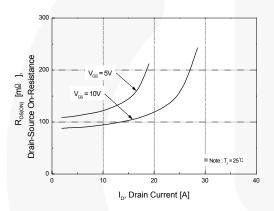


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

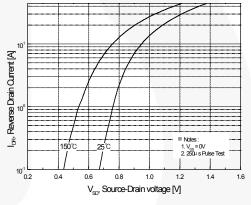


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

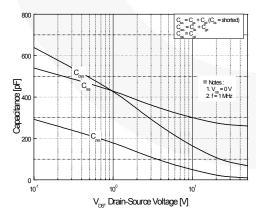


Figure 5. Capacitance Characteristics

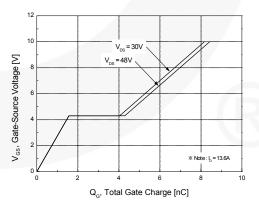


Figure 6. Gate Charge Characteristics

12 BA (150) BY (150) BY

0.8 L -100

-50

Typical Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

T,, Junction Temperature [°C]

100

150

200

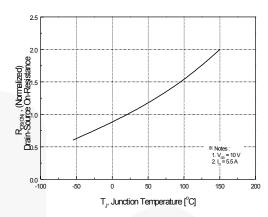


Figure 8. On-Resistance Variation vs. Temperature

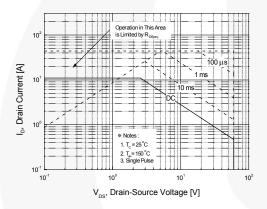


Figure 9. Maximum Safe Operating Area

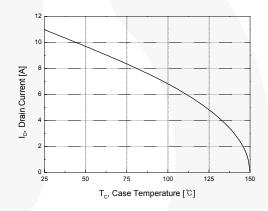


Figure 10. Maximum Drain Current vs. Case Temperature

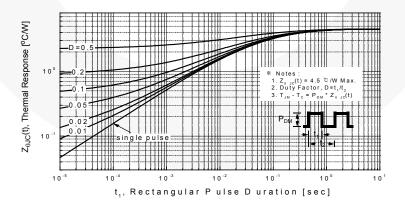


Figure 11. Transient Thermal Response Curve

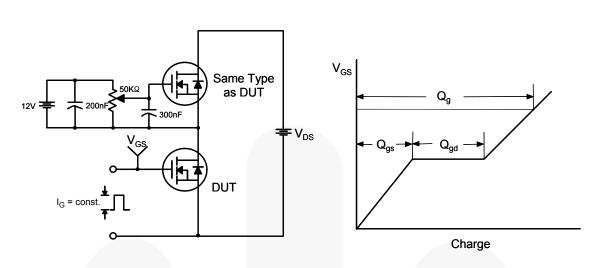


Figure 12. Gate Charge Test Circuit & Waveform

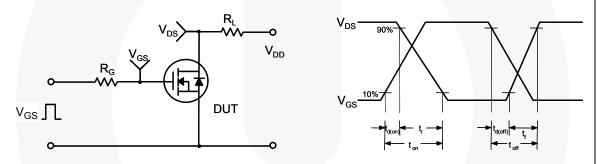


Figure 13. Resistive Switching Test Circuit & Waveforms

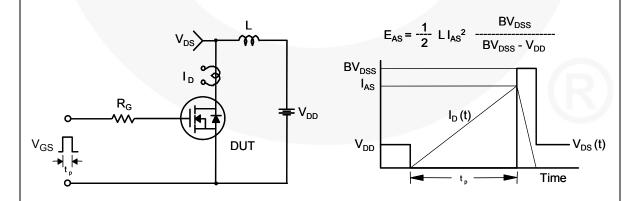
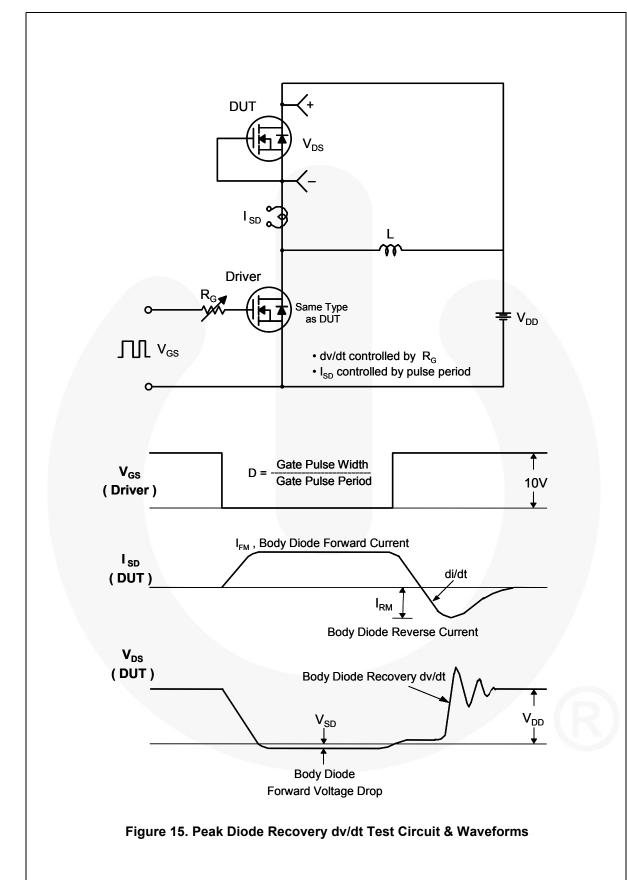
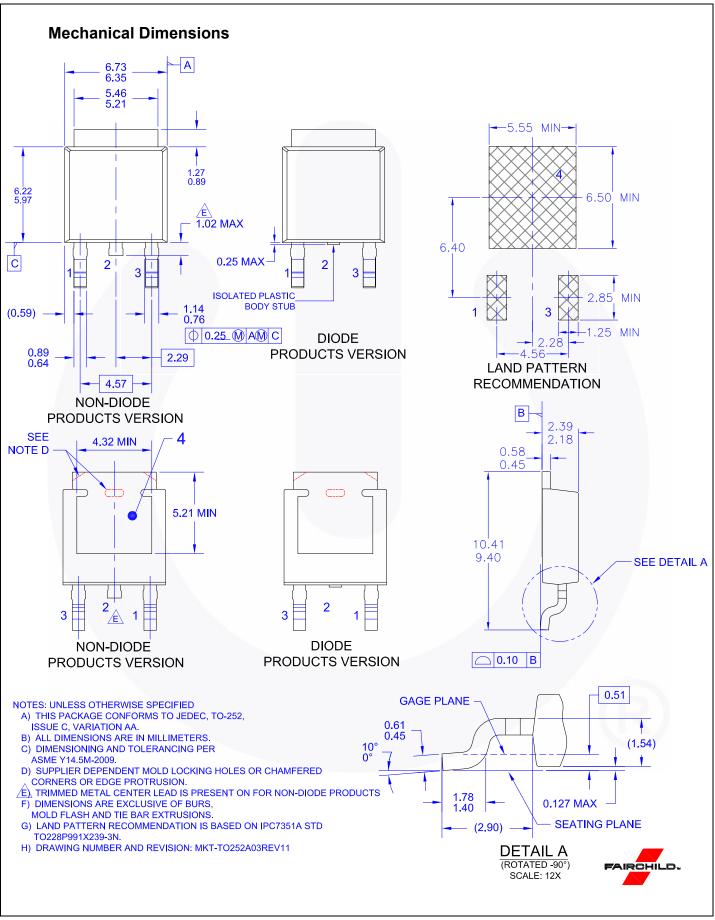


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms





Mechanical Dimensions

FQU13N06LTU

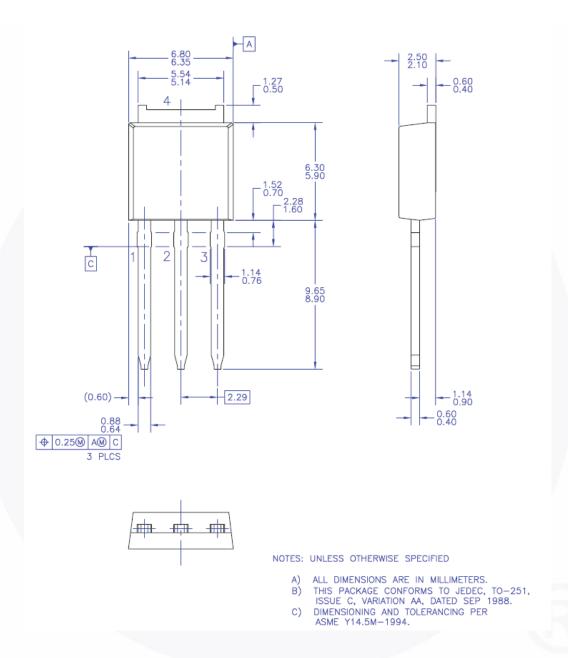


Figure 17. TO251 (I-PAK), Molded, 3-Lead

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Mechanical Dimensions

FQU13N06LTU_WS

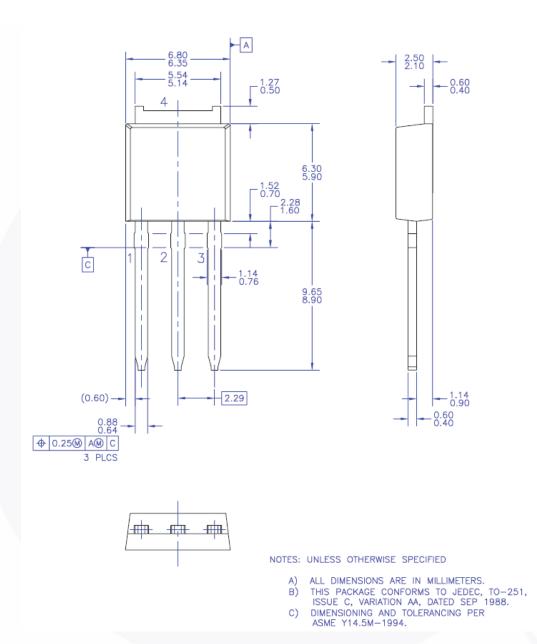


Figure 18. TO-251 (I-PAK), Molded, 3-Lead, Option AA

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